

MPSA43

NPN High Voltage Amplifier

- This device is designed for application as a video output to drive color CRT and other high voltage applications.
- Sourced from process 48.
- · See MPSA42 for characteristics.



1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings * T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	200	V
V_{CBO}	Collector-Base Voltage	200	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector Current - Continuous	200	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	Off Characteristics				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	200		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100\mu A, I_E = 0$	200		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_C = 100 \mu A, I_C = 0$	6.0		V
I _{CBO}	Collector Cutoff Current	V _{CB} = 160V, I _E = 0		0.1	μΑ
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 4.0V, I_{C} = 0$		0.1	μΑ
On Charac	cteristics *			•	-
h _{FE}	DC Current Gain	$I_C = 1.0$ mA, $V_{CE} = 10$ V $I_C = 10$ mA, $V_{CE} = 10$ V $I_C = 30$ mA, $V_{CE} = 10$ V	25 40 50	200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 20mA, I _B = 2.0mA		0.4	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 20mA, I _B = 2.0mA		0.9	V
Small Sign	nal Characteristics *				
f _T	Current Gain Dandwidth Product	$I_C = 10 \text{mA}, V_{CE} = 20 \text{V}, f = 100 \text{MHz}$	50		MHz
C _{cb}	Collector-Base Capacitance	$V_{CB} = 20V, I_E = 0, f = 1.0MHz$		4.0	pF
Pulse Test: Pu	lse Width ≤ 300μs, Duty Cycle ≤ 2.0%	-		•	•

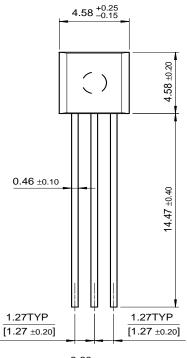
Thermal Characteristics T_A=25°C unless otherwise noted

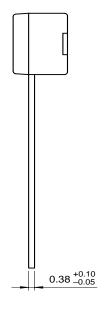
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

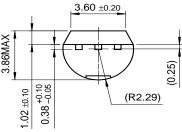
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Package Dimensions

TO-92







Dimensions in Millimeters

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